



Specification for a Sinewave Output Thru-Hole OCXO MtronPTI P/N: XO5085-071R

Electrical Specifications:

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Nominal Frequency	FO		100.0000		MHz	
· ·	-		Frequency Stab	ilities		
ve Temperature	۸ F - / F	-100		+100	ppb	Over the Operating
vs. Temperature	ΔFT/F					Temperature Range
vs. Supply voltage		-30		+30	ppb	5% change in supply
variation						voltage
Daily Aging		-5		+5	ppb	_
1 Year Aging		-0.5		+0.5	ppm	After 30-days Power On
20-Years Aging		-2.0		+2.0	ppm	
			RF Output		1	
Output Type			Sinewave	1		
Output Level			7		dBm	
Output Load			50		Ω	±10%
		F	requency Adjus			
Adjustment Method			External	Voltage		
Adjustment Voltage	VTUNE	0		+5	VD	
Adjustment Range		±1.5			ppm	Over all conditions
Adjustment Slope			Posit			
			Additional Parar			
				-97	dBc/Hz	10Hz Offset
Phase Noise				-128	dBc/Hz	100Hz Offset
(Under Static				-155	dBc/Hz	1kHz Offset
Conditions)				-160	dBc/Hz	10kHz Offset
				-170	dBc/Hz	100kHz Offset
				-170	dBc/Hz	1MHz Offset
				-170	dBc/Hz	10MHz Offset
Harmonics				-25	dBc	
Spurious				-75	dBc	
Warm-up Time						To within ±0.1ppm of the
				5	minutes	frequency after 1-hour
						of operation @ 25°C
	Temr	perature Su	pply Voltage & I	Power Consu	mntion	
Operating Temperature	OTR	-40	Phil Ange of I	+85	°C	Full Specification
Operating remperature		-40		.05		Compliance
Storage Temperature	STR	-55		+85	°C	
Operating Voltage	VCC	+4.75	+5.0	+5.25	VD	
operating voltage		· - .73	1.5	.3.23		Steady state @ 25°C,
Power Consumption			1.5		Watts	In Still Air
				4.0	Watts	@Warm-up



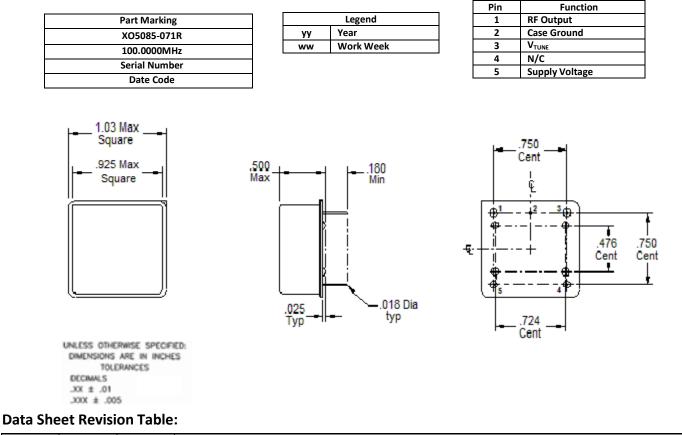


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Environmental Conditions:

Seal	Hermetic	
RoHS	Full RoHS Compliance	

Mechanical, Marking and Layout Information:



Date	Rev.	Orig.	Details of Revision
03-17-17	A	DPD	Original release